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## F. Silicon and Group-IV Devices and Integration Technology 분과 [TF2-F] Intergration Technology

TF2-F-1 14:10-14:40	[초청] Highly CMOS Compatible Strategies for Extending Moore's Law Sangwan Kim, Seong-Su Shin, Hwa Young Gu, and Shinhee Kim Department of Electrical and Computer Engineering, Ajou University
TF2-F-2 14:40-15:10	[초청] Hafnia Ferroelectric Device for Logic and Memory Applications Sanghun Jeon Department of Applied Physics, Korea University
TF2-F-3 15:10-15:25	Monolithic 3D CMOS-Nanoelectromechanical (NEM) Hybrid Circuits Hyug Su Kwon, Seung Kyu Kim, and Woo Young Choi Department of Electronic Engineering, Sogang University
TF2-F-4 15:25-15:40	Operating Voltage Analysis of CMOS-Nano-Electromechanical (NEM) Hybrid Circuits Ho Moon Lee and Woo Young Choi Department of Electronic Engineering, Sogang University
TF2-F-5 15:40-15:55	Novel Packaging Method of CMOS-Nano-Electromechanical (NEM) Hybrid Circuits  Hyun Chan Jo and Woo Young Choi  Department of Electronic Engineering, Sogang University